

Vishay Semiconductors

ADD-A-PAK Generation VII Power Modules Standard Diodes, 60 A



ADD-A-PAK

PRODUCT SUMMARY				
I _{F(AV)}	60 A			
Туре	Modules - Diode, High Voltage			

MECHANICAL DESCRIPTION

The ADD-A-PAK generation VII, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

FEATURES

- · High voltage
- Industrial standard package
- · Low thermal resistance
- UL approved file E78996
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified for industrial level

BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- Up to 1600 V
- · High surge capability
- · Easy mounting on heatsink

ELECTRICAL DESCRIPTION

These modules are intended for general purpose high voltage applications such as high voltage regulated power supplies, lighting circuits, temperature and motor speed control circuits, UPS and battery charger.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	114 °C	60				
I _{F(RMS)}		94	Α			
I _{FSM}	50 Hz	1300	A			
	60 Hz	1360				
l ² t	50 Hz	8.44	kA ² s			
I-1	60 Hz	7.68	KA-S			
l ² √t		84.5	kA²√s			
V _{RRM}	Range	400 to 1600	V			
T _J		- 40 to 150	°C			
T_{Stg}		- 40 to 150				

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ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS							
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J = 150 °C mA			
	04	400	500				
	06	600	700				
	80	800	900				
VSK.56	10	1000	1100	10			
	12	1200	1300				
	14	1400	1500				
	16	1600	1700				

FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum average forward current at case temperature	I _{F(AV)}	180° condu	180° conduction, half sine wave		60	A
·					114	°C
Maximum RMS forward current	I _{F(RMS)}	DC at 90 °C	case temperat	ure	94	
		t = 10 ms	No voltage		1300	
Maximum peak, one-cycle forward,		t = 8.3 ms	reapplied		1360	Α
non-repetitive surge current	I _{FSM}	t = 10 ms	100 % V _{RRM}		1090	
		t = 8.3 ms	reapplied	Sinusoidal half wave,	1140	
	l²t	t = 10 ms	No voltage	intitial $T_J = T_J$ maximum	8.44	
Marrian na 121 fau frainn		t = 8.3 ms	reapplied		7.68	kA ² s
Maximum I ² t for fusing		t = 10 ms	100 % V _{RRM}		5.97	KA ² S
		t = 8.3 ms	reapplied		5.43	1
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms t	t = 0.1 ms to 10 ms, no voltage reapplied			kA²√s
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % x π	$x I_{F(AV)} < I < \pi x$	$(I_{F(AV)}), T_J = T_J \text{ maximum}$	0.74	V
High level value of threshold voltage	V _{F(TO)2}	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$			0.86	V
Low level value of forward slope resistance	r _{f1}	(16.7 % x π x $I_{F(AV)} < I < \pi$ x $I_{F(AV)}$), $T_J = T_J$ maximum		3.94	mΩ	
High level value of forward slope resistance	r _{f2}	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$			3.43	1115.2
Maximum forward voltage drop	V_{FM}	$I_{FM} = \pi \times I_{F(A)}$	_{AV)} , T _J = 25 °C,	t _p = 400 μs square wave	1.6	V

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum peak reverse leakage current	I _{RRM}	T _J = 150 °C	10	mA
Maximum RMS insulation voltage	V _{INS}	50 Hz	3000 (1 min) 3600 (1 s)	V



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THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	SYMBOL TEST CONDITIONS		UNITS	
Junction and storage temp	erature range	T _J , T _{Stg}		- 40 to 150	°C	
Maximum internal thermal junction to case per leg	esistance,	R _{thJC}	DC operation	0.33	°C/W	
Typical thermal resistance, case to heatsink per module		R _{thCS}	Mounting surface flat, smooth and greased	0.1	C/VV	
Mounting torque ± 10 % busbar			A mounting compound is recommended and the	4	NI	
			torque should be rechecked after a period of 3 hours to allow for the spread of the compound.	3	Nm	
Approximate weight				75	g	
				2.7	OZ.	
Case style			JEDEC	ADD-A-PAK Ger	n. VII (TO-240AA	

△R CONDUCTION PER JUNCTION											
DEVICES		SINE HALF	WAVE CO	NDUCTIO	N	RECTANGULAR WAVE CONDUCTION				UNITS	
DEVICES	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	UNITS
VSK.56	0.115	0.136	0.173	0.236	0.346	0.09	0.145	0.185	0.243	0.349	°C/W

Note

• Table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

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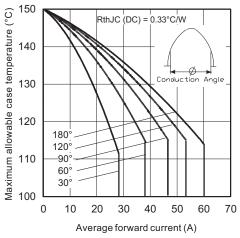


Fig. 1 - Current Ratings Characteristics

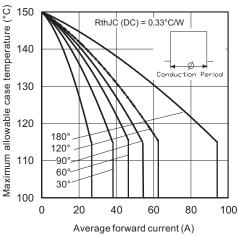


Fig. 2 - Current Ratings Characteristics

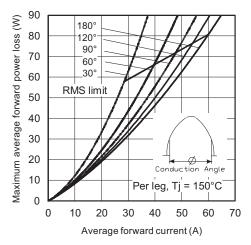


Fig. 3 - Forward Power Loss Characteristics

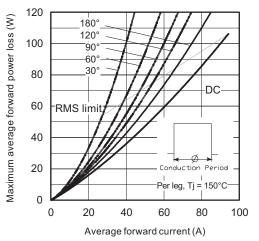


Fig. 4 - Foward Power Loss Characteristics

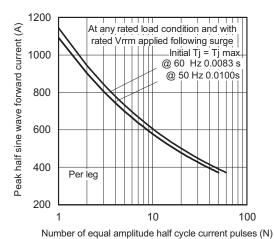


Fig. 5 - Maximum Non-Repetitive Surge Current

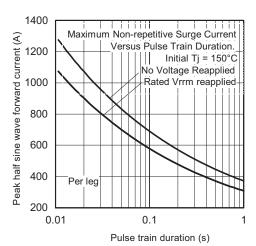


Fig. 6 - Maximum Non-Repetitive Surge Current



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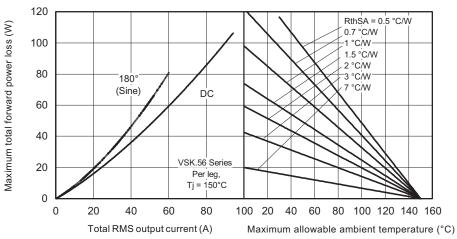


Fig. 7 - Forward Power Loss Characteristics

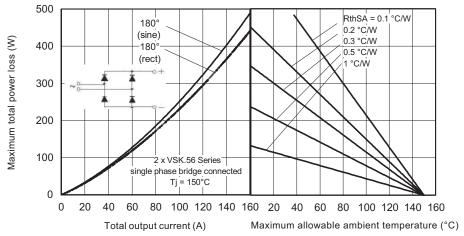


Fig. 8 - Forward Power Loss Characteristics

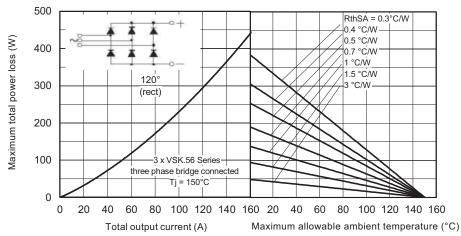


Fig. 9 - Forward Power Loss Characteristics

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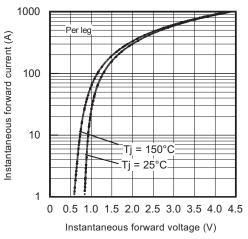


Fig. 10 - Forward Voltage Characteristics

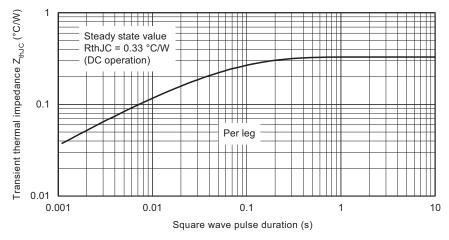


Fig. 11 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

- 1 Module type
- 2 Circuit configuration (see Circuit Configuration table)
- 3 Current code (60 A)
- 4 Voltage code (see Voltage Ratings table)

Note

• To order the optional hardware go to www.vishay.com/doc?95172



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CIRCUIT CONFIGURATION		
CIRCUIT DESCRIPTION	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING
Two diodes doubler circuit	D	VSKD (1) ~ (2) ~ (3)
Two diodes common cathodes	С	VSKC (1) 0 (2) (3)
Two diodes common anodes	J	VSKJ (1) (2) - (3)
Single diode	E	VSKE (2) 0

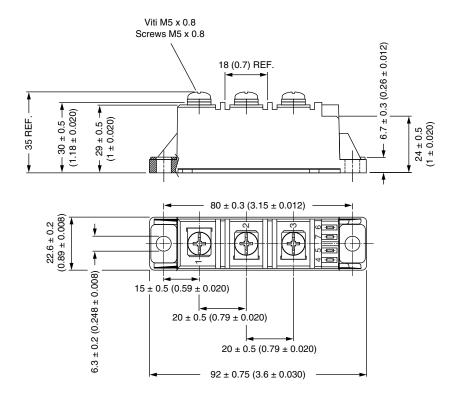
LINKS TO RELAT	FED DOCUMENTS
Dimensions	www.vishay.com/doc?95369



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ADD-A-PAK Generation VII - Diode

DIMENSIONS in millimeters (inches)





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